TOSHIBA Transistor Silicon NPN Triple Diffused Type

# 2SC5198

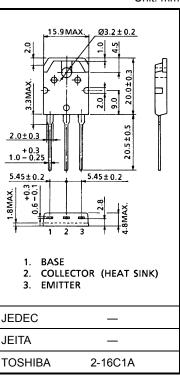
### **Power Amplifier Applications**

• High breakdown voltage: VCEO = 140 V (min)

- Complementary to 2SA1941
- Suitable for use in 70-W high fidelity audio amplifier's output stage

#### Maximum Ratings (Tc = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	140	V
Collector-emitter voltage	V <sub>CEO</sub>	140	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	Ι <sub>C</sub>	10	А
Base current	Ι <sub>Β</sub>	1	А
Collector power dissipation (Tc = 25°C)	Pc	100	W
Junction temperature	Тј	150	°C
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C



### **Electrical Characteristics (Tc = 25°C)**

Weight: 4.7 g (typ.)

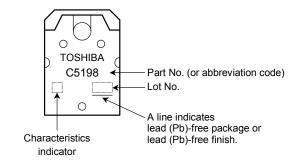
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 140 V, I <sub>E</sub> = 0	_	_	5.0	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	_	_	5.0	μA
Collector-emitter breakdown voltage	V (BR) CEO	I <sub>C</sub> = 50 mA, I <sub>B</sub> = 0	140	—		V
DC current gain	h <sub>FE (1)</sub> (Note)	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A	55	_	160	
	h <sub>FE (2)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 5 A	35	83	_	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 7 A, I <sub>B</sub> = 0.7 A	—	0.3	2.0	V
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 5 A	_	0.9	1.5	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A	_	30	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	170	_	pF

Note: hFE (1) classification R: 55 to 110, O: 80 to 160

Unit: mm

# **TOSHIBA**

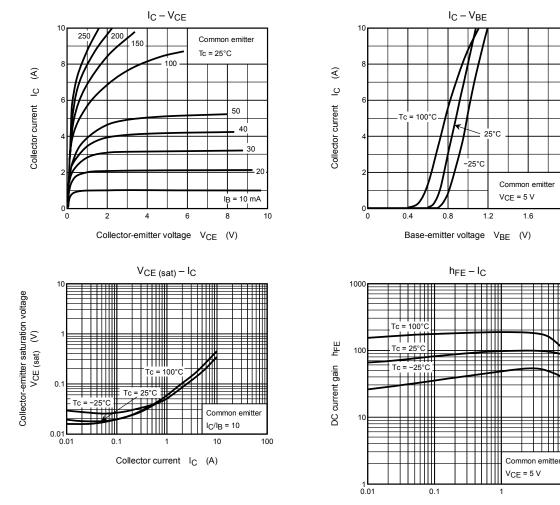
## Marking



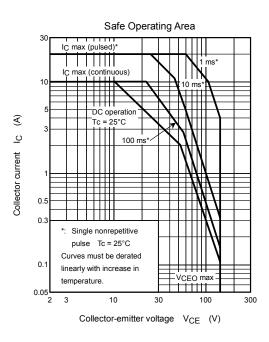
# **TOSHIBA**

2.0

10



Collector current  $I_C$  (A)



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